ECE113: Basic Electronics

Lecture 1: Introductory remarks, Course information and assessments

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INDRAPRASTHA INSTITUTE of INFORMATION TECHNOLOGY **DELHI**



About the instructor



- Name: Ram Krishna Ghosh
- **Designation**: Assistant Professor
- PhD: Indian Institute of Science, Bangalore
- Masters: IIT Madras
- Research Interest: Computational nanoelectronics, spintronics, quantum transport simulation, device modeling, materials modeling, and multiscale modeling
- Website: https://www.iiitd.ac.in/rkghosh
- Courses:
 - Quantum Materials and Devices (Monsoon)
 - Basic Electronics (Winter), for B.Tech 1st yr. students

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More TAs will join soon...

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More TAs will join soon...

Course Outline



- Basic components of Electrical Circuits: Fundamental Electrical variables charge, current, voltage and power; independent and dependent voltage and current sources, Ideal circuit elements – Resistor, Capacitor and Inductor. Constitutional relationship – Ohms Law;
- Basic concepts of Analysis of Resistive Networks: Nodes, Paths and Loops, Kirchoff's Voltage and Current Laws, Series and Parallel connection of Resistances and division voltage and current. Loop and Node Analysis.

Network Theorems: Thevenin's Theorem, Norton's Theorem

Course Outline



- Superposition Theorem and Maximum Power Transfer Theorem.
- RC and RL circuits' response to Step and Direct input
- RLC circuits' response to Step and Direct input
- Concepts of impedance/admittance, Phasors and Representation
- RC, RL and RLC circuits' response to Alternating inputs (the response to alternating input will be handled only under steady state condition)

Course Outline



- Passive and Active Components: Operational Amplifier Inverting configuration
- Operational Amplifier Non-Inverting, Integrating and Differentiating configuration
- Diodes: Basic principle, Clipper, Clamper circuits and application
- LED, Zener Diode and Solar Cell
- Half Wave and Full Wave Rectifiers Wave form and Ripple & its reduction.

Text books:



- William H. Hayt Jr., Jack E. Kemmerly and Steven M. Durbin, *Engineering Circuit analysis*. 8th Edition, Tata McGraw Hill
- Sedra, A. S. and Smith, K. C., *Microelectronic circuits*. 6th Edition, Oxford University Press

There are many text for Principles of Electrical Engineering.

Assessment



•	Assignments	15%

- Class tests 15%
- Laboratory 20%
- Mid Semester 20%
- End Semester 30%

Course communication



- All the announcements, assignments, lectures, lab materials will be shared through **google classroom**.
- No separate commutations shall be done using email, unless necessary.
- Consult course site at google classroom regularly

How to Join ECE113- Basic Electronics Section B in google classroom



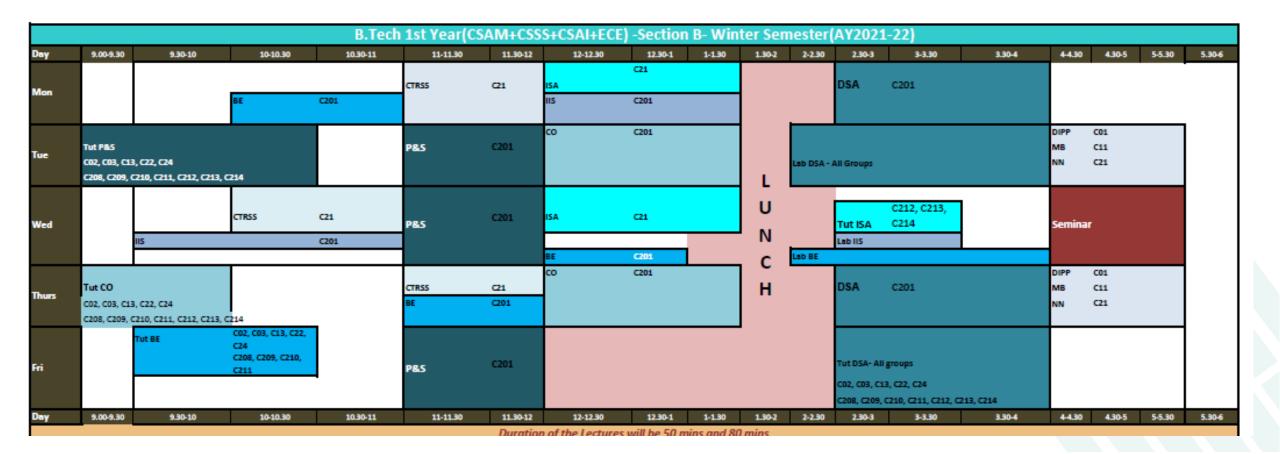
- Log on to google classroom using your IIITD credentials
- Click on the + sign at the top right corner
- Select join class
- Link: https://classroom.google.com/u/2/c/NDg1MDUxMTY4MjA1
- Enter this class code: iqfn3vt

Time table



Class: Monday 10 am – 11 am; Wednesday 12 pm – 1 pm, and Thursday 11 am -12 pm

Lab: Thursday 2 pm – 4 pm



Lab



- Location: We will have offline laboratory Session
- Lab materials will be provided through google classroom
- From next week onward: prepare for the lab beforehand

Ground rules



- Be on time
- Bring your own calculator
- Keep mobile phone in silence mode and inside your bag
- Do not contain a discussion among your peers,
- let the rest of the class know what are your concerns (may be some other students have similar concerns too!)
- IIIT Delhi plagiarism policy will be strictly followed in this class

IIITD plagiarism policy



	Misconduct/use of unfair means in	Penalty
	assignments/projects	
1.	First misconduct/use of unfair means	Zero in the assignment (awarded by
	during the entire stay in IIIT-Delhi	faculty) + one letter grade less in the
		course.
2.	Second misconduct/use of unfair means	Student is assigned an F grade in the
	during entire stay in IIIT-Delhi	course.
3.	Third or further misconduct/use of unfair	Student is assigned an F grade in the
	means during the entire stay in IIIT-Delhi	course and the case is reported to DAC,
		who may suspend the student for 1
		semester to a year.

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IIITD plagiarism policy

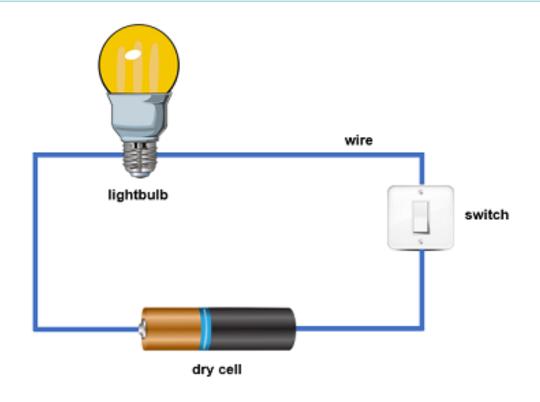


	Misconduct/use of unfair means in	Penalty
	quiz/midsem/endsem	
1.	First misconduct/use of unfair means	Student is assigned an F grade in the
	during the entire stay in IIIT-Delhi	course.
2.	Second misconduct/use of unfair means	Student is assigned an F grade in the
	during the entire stay in IIIT-Delhi	course and student may be suspended
		from the program for 1-2 semesters by
		DAC.
3.	Third misconduct/use of unfair means	Student is assigned an F grade in the
	during the entire stay in IIIT-Delhi	course and student's program may be
		terminated by DAC.

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Electronics





Electronics: Deals with design development and application of electron devices

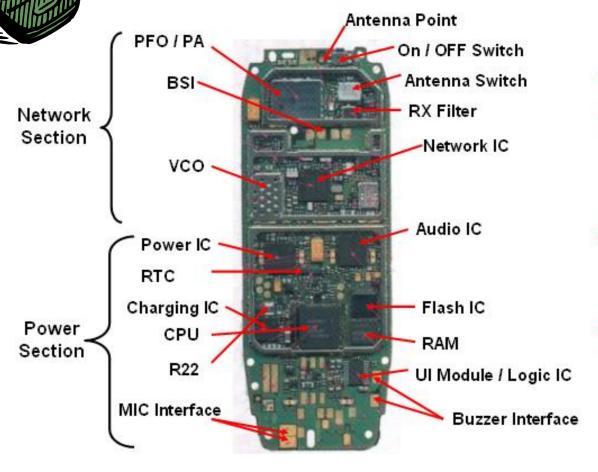
Electron Devices: A device in which electron or electrical conduction takes place through vacuum, gas or semiconductor



Example electronic system: cell phone

Mobile Phone PCB Diagram

www.mobilecellphonerepairing.com

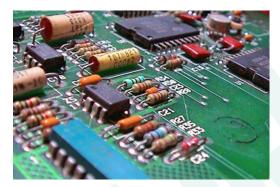


NOTES:

- . UEM =
 - Logic IC
 - + Charging IC
 - + Audio IC
 - + Power IC
- 2. PFO =

Antenna Switch

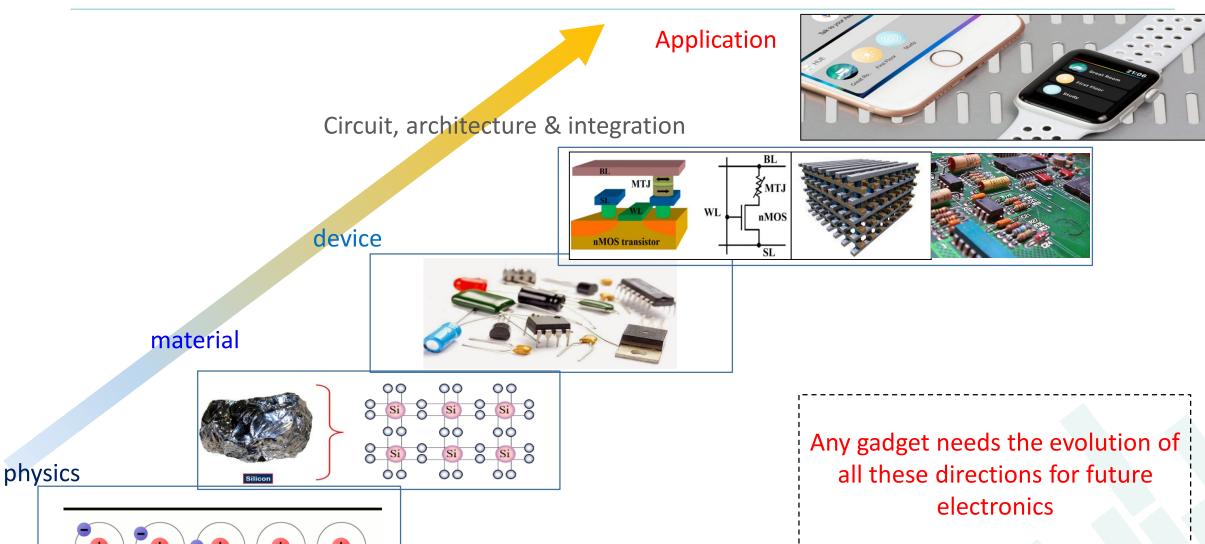
- + PFO
- B. Flash IC = RAM + Flash IC

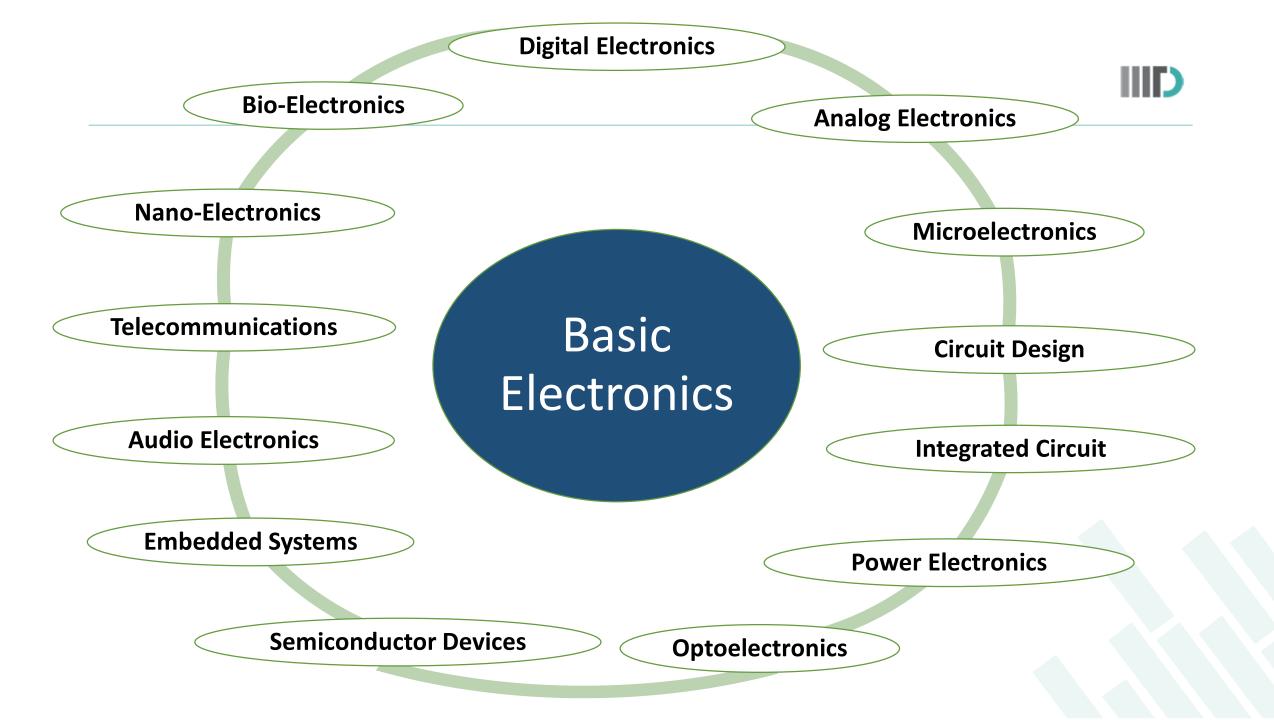


Printed circuit board: A board made for connecting electronic components together

Semiconductor technology hierarchy

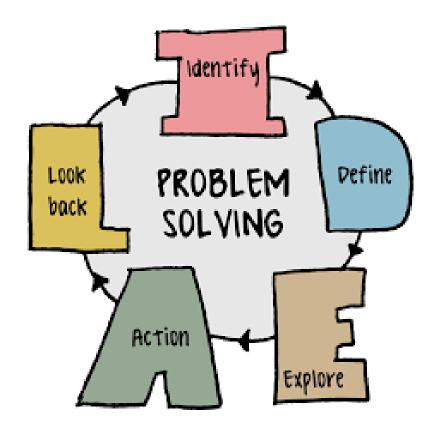






Motivation



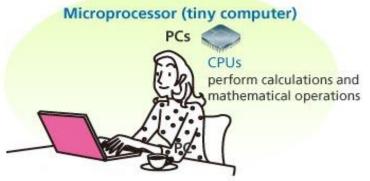


Motivation













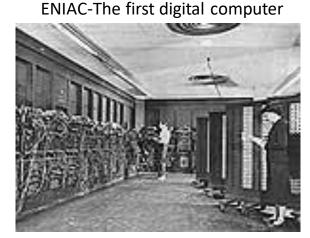


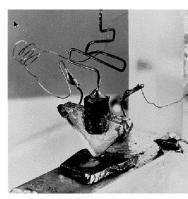
Early History of Semiconductor Devices



1940's: Vacuum-tube era

- Vacuum tubes were used for radios, television, telephone equipment, and computers
- ... but they were expensive, bulky, fragile, and energy-hungry
- → Invention of the point-contact transistor
 - Walter Brattain, John Bardeen, and William Shockley, Bell Labs, 1947
 Nobel Prize in Physics 1956
 - reproducibility was an issue, however
- → Invention of the bipolar junction transistor (BJT)
 - William Shockley, Bell Labs, 1950
 - more stable and reliable; easier and cheaper to make





Discrete Electronic Circuits



• In 1954, Texas Instruments produced the first commercial silicon transistor.



~\$2.50 each

Before the invention of the integrated circuit, electronic equipment was composed of discrete components such as transistors, resistors, and capacitors. These components, often simply called "discretes", were manufactured separately and were wired or soldered together onto circuit boards. Discretes took up a lot of room and were expensive and cumbersome to assemble, so engineers began, in the mid-1950s, to search for a simpler approach...

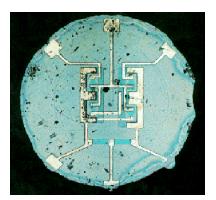
The Integrated Circuit (IC)



- An IC consists of interconnected electronic components in a single piece ("chip") of semiconductor material.
 - In 1958, Jack S. Kilby (Texas Instruments) showed that it was possible to fabricate a simple IC in germanium.



 In 1959, Robert Noyce (Fairchild Semiconductor) demonstrated an IC made in silicon using SiO₂ as the insulator and Al for the metallic interconnects.

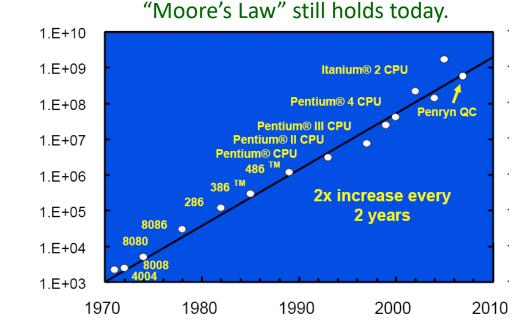


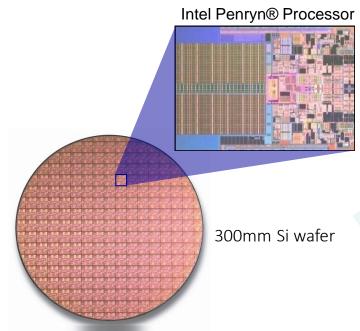
The first planar IC (actual size: ~1.5mm diameter)

From a Few, to Billions of Components



- By connecting a large number of components, each performing simple operations, an IC that performs complex tasks can be built.
- The degree of integration has increased at an exponential pace over the past ~40 years.
 - The number of devices on a chip doubles every ~2 years, for the same price.







The Silicon Revolution



- Steady progress in integrated-circuit technology over 40+ years has had dramatic impact on the way people live, work, and play.
- The semiconductor industry is approaching \$300B/yr in sales:



Military 2%



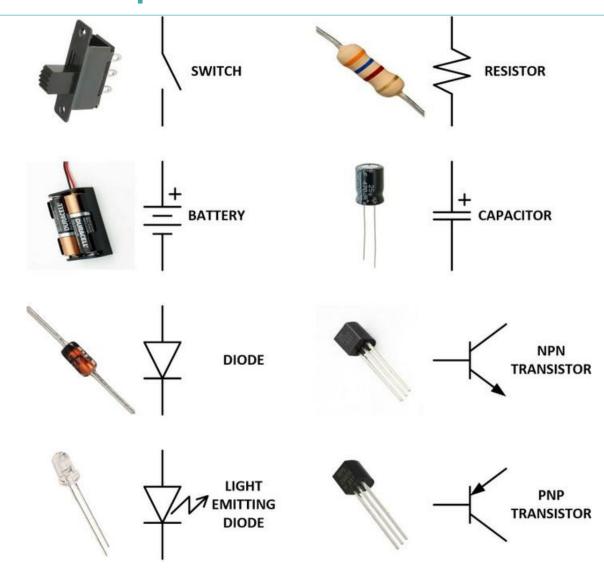
Industrial 8%





Electronic components





Electrical quantities



- Charge: unit Coulomb
- Current: unit Ampere
- Voltage: unit Volt
- Power: unit Watt
- Resistance: unit Ohm

Charge



- A physical property of matter which interacts with electromagnetic field
 - Experiences a force due to a electromagnetic field
 - Responsible for creating electric field
- The force can be calculated using Coulomb's Law:

$$F = \frac{Kq_1q_2}{d^2}$$

Notice the similarity with Newton's Law of Gravitation

- Two types of charges: +ve and –ve
- Same types of charges repel and unlike types attract
- Convention: charge of a proton is +ve and that of an electron is -ve

Charge



- Unit : Coulomb (C)
- -ve charge of an electron = 1.602×10^{-19} C

Notation convention:

Constant charge is represented as Q and time varying charge is represented as q(t)

Current



- Electric/ electronic circuits' function depends on flow of charge
- Current is defined as the instantaneous rate at which net positive charge move past a specific point/ cross-section at a specific direction:

$$i = \frac{dq}{dt}$$

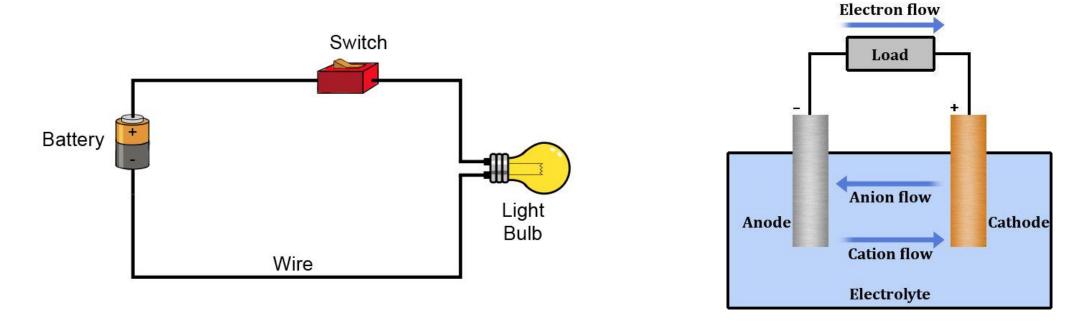
- Unit: Ampere (A): 1 C/s
- Can vary with time (unless DC, in ideal case)

A current of 5 A flows for 2 minutes in a circuit, find the quantity of electricity transferred.

Quantity of electricity Q=It coulombs I=5 A, $t=2\times60=120$ s Hence $Q=5\times120=600$ C

Conservation of charge





• Total electric charge is *conserved* in nature in the following sense: if a process generates (or eliminates) a positive charge, it always does so as accompanied by a negative charge of equal magnitude.

Continuity equation



• Consider two distinct surfaces S_1 and S_2 bounded by the same closed loop C (as shown in the margin) such that a volume V is contained between the two surfaces.

- Let

$$I_1 = \int_{S_1} \mathbf{J} \cdot d\mathbf{S}_1$$

and

$$I_2 = \int_{S_2} \mathbf{J} \cdot d\mathbf{S}_2$$

denote currents flowing through surfaces S_1 and S_2 , respectively.

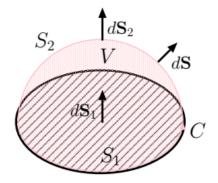
- Note that current I_1 through surface S_1 enters volume V, while current I_2 through surface S_2 exits volume V (with the directions assigned to $d\mathbf{S}_1$ and $d\mathbf{S}_2$).
- If $I_1 \neq I_2$, then **current out** is not matched by the **current in**, and as a result, the net charge Q_V contained in volume V increases with time at a rate $I_1 I_2$ provided that charge is *conserved* in the sense discussed above. In that case, we have

$$\frac{dQ_V}{dt} = I_1 - I_2.$$

This relationship can be expressed as

$$\frac{d}{dt} \int_{V} \rho dV = \int_{S_1} \mathbf{J} \cdot d\mathbf{S}_1 - \int_{S_2} \mathbf{J} \cdot d\mathbf{S}_2$$

Current I out of a volume is equal to rate of decrease of charge Q contained in that volume:



since, in terms of charge density ρ , charge in volume V is

$$Q_V = \int_V \rho dV.$$

The expression can also be cast as

$$\int_{V} \frac{\partial \rho}{\partial t} dV = -\oint_{S} \mathbf{J} \cdot d\mathbf{S}$$

where S is the union of surfaces S_1 and S_2 enclosing V, and $d\mathbf{S}$ is an outward area element of S (see margin). This relationship is known as **continuity equation**. Its differential form is

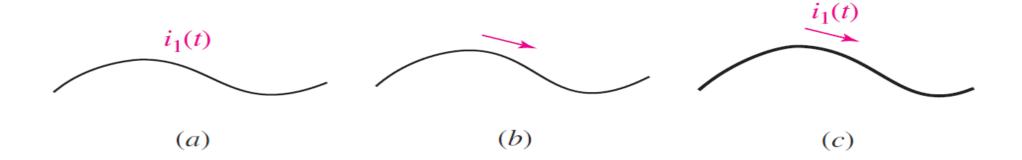
Continuity equation

$$\frac{\partial \rho}{\partial t} = -\nabla \cdot \mathbf{J},$$

Current representation



Direction is important



c) Is the correct representation

Current representation





Both are same

Types of current



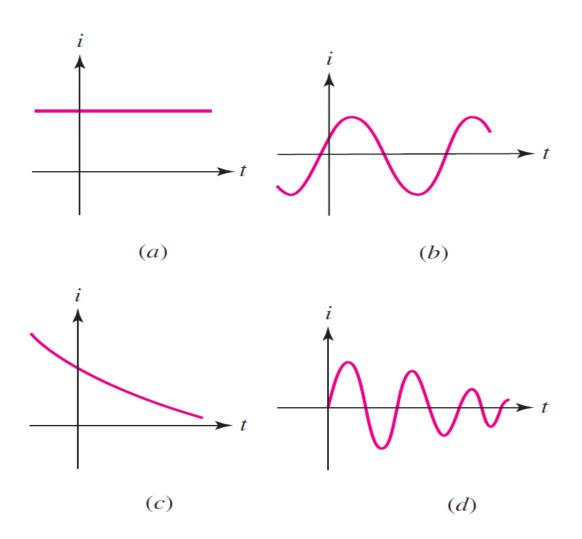


FIGURE 2.4 Several types of current: (a) Direct current (dc). (b) Sinusoidal current (ac).
(c) Exponential current. (d) Damped sinusoidal current.

Voltage



To describe the rigorous definition of voltage, we must define Electric Potential

- Electric Potential: -ve of line integral of electric field over a path
- Voltage: Difference in potential between two points
- Essentially this is the work required to move an unit charge from one point to another
- Unit: Volt (V) Work required is 1 Jule to move 1 C charge

Voltage



The unit of electric potential is the volt (V), where one volt is one joule per coulomb. One volt is defined as the difference in potential between two points in a conductor which, when carrying a current of one ampere, dissipates a power of one watt, i.e.

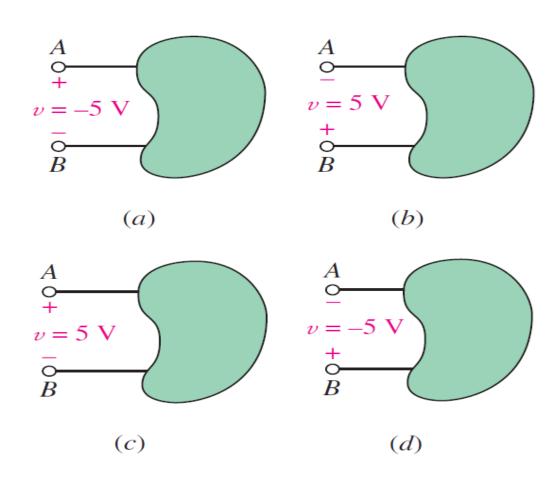
$$volts = \frac{Watt}{amperes} = \frac{\frac{joules}{second}}{ampere}$$
$$= \frac{joules}{amperes seconds} = \frac{joules}{coulombs}$$

A change in electric potential between two points in an electric circuit is called a potential difference and its unit is Volt.

The electromotive force (e.m.f.) provided by a source of energy such as a battery or a generator is measured in volts.

Voltage representation





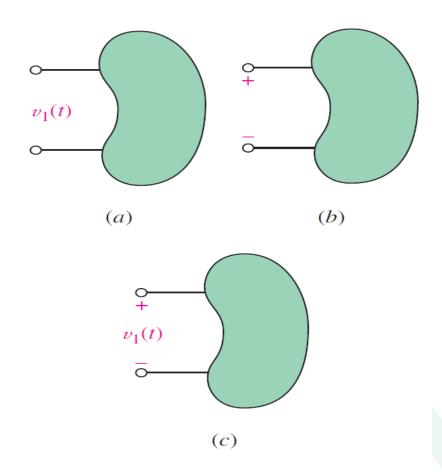


FIGURE 2.10 (*a, b*) These are inadequate definitions of a voltage. (*c*) A correct definition includes both a symbol for the variable and a plus-minus symbol pair.

Power



Power: rate of work done (transferring energy)

$$P = \frac{W}{t} = \frac{W}{q} \cdot \frac{q}{t} = vi$$

• Unit: Watt – 1 J/s

Electrical energy = Power \times time = V I X t joules

Although the unit of energy is the joule, when dealing with large amounts of energy the unit used is the kilowatt hour (kWh)

where 1kWh = 1000 watt hour = 1000×3600 watt seconds (joules) = 3600 000 J

Passive sign convention



Power absorbed by the element p = v i We can also be say that element generates or supplies a power of -v i

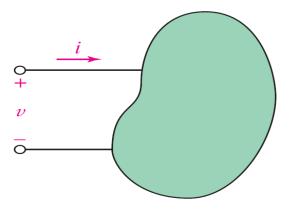


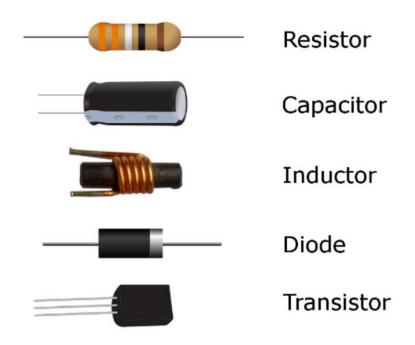
FIGURE 2.12 The power absorbed by the element is given by the product p = vi. Alternatively, we can say that the element generates or supplies a power -vi.

- When the current arrow is directed into the element at the plus-marked terminal, we satisfy the
 passive sign convention.
- If the current arrow is directed into the "+" marked terminal of an element, then p = vi yields the absorbed power. A negative value indicates that power is actually being generated by the element.
- If the current arrow is directed out of the "+" terminal of an element, then p = vi yields the supplied power. A negative value in this case indicates that power is being absorbed.

Circuit Elements



- Passive elements component that does not generate power / cannot amplify or rectify a.c. power
- Active Elements capable of generating electrical energy / can amplify or rectify a.c. power



Circuit Elements

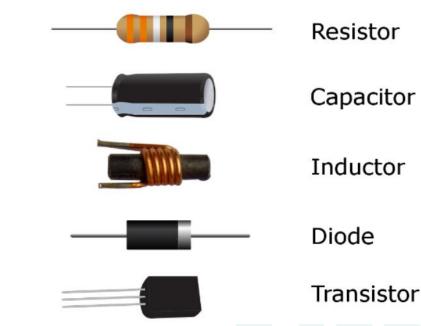


 Linear circuit elements — Resistor, capacitors, and inductors are called linear circuit elements as the current —voltage relationship is linear in these elements

Nonlinear circuit elements— In diodes and transistors, the current—voltage relationship is not linear and they called nonlinear circuit

elements.

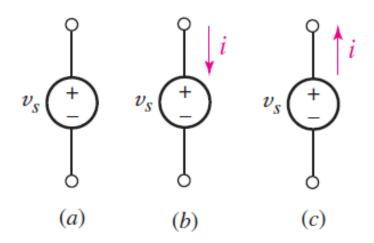
Ohm's law, Kirchhoff's laws are not applicable to circuits involving nonlinear elements. However, in many electronic circuits under certain operating conditions the nonlinear elements are replaced by some linear but equivalent circuits and then are analyzed by the known laws of electrical circuits.

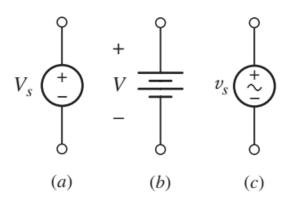


Independent Voltage Source



- Terminal voltage is completely independent of the current
- + sign is a reference, does not necessarily mean that upper terminal is numerically +ve
- This is a theoretical notion, a mathematical model that can be used for further analysis



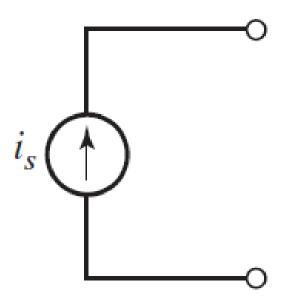


■ **FIGURE 2.16** (*a*) DC voltage source symbol; (*b*) battery symbol; (*c*) ac voltage source symbol.

Independent Current Source



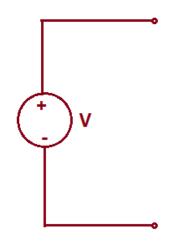
- Current is completely independent of the terminal voltage
- Again a theoretical notion
- Arrow denotes the direction
- Does not necessarily mean that terminal voltage difference will be 0
- Direction: +ve to –ve is +
- Direction: -ve to +ve is -

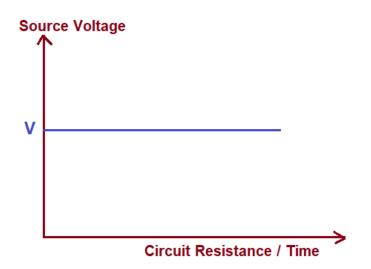


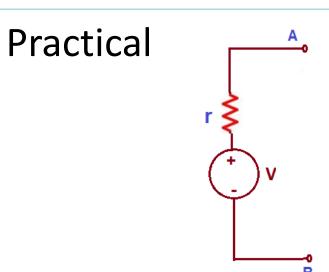
Practical voltage source

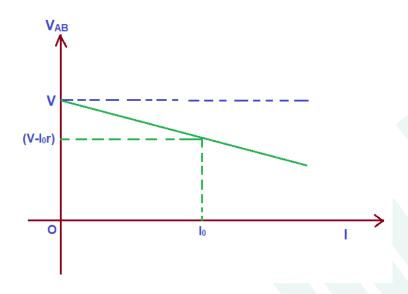


Ideal





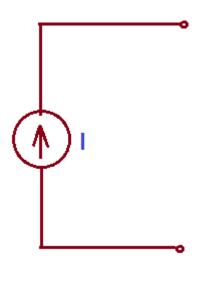


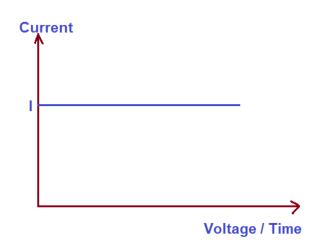


Practical current source

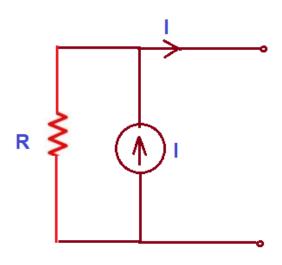


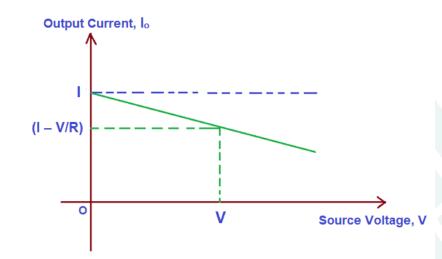
Ideal





Practical





Dependent Sources



- These are also ideal sources
- Dependent on current or voltage at some other area of the circuit
- Again independent of terminal voltage/current

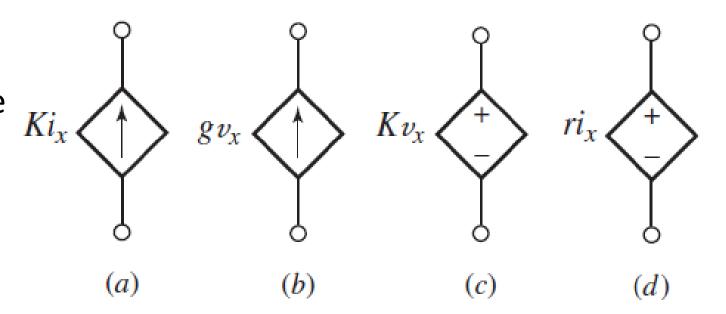


FIGURE 2.18 The four different types of dependent sources: (a) current-controlled current source; (b) voltage-controlled current source; (c) voltage-controlled voltage source; (d) currentcontrolled voltage source.

K is a dimensionless scaling const. g is a scaling factor with units of A/V and r is a scaling factor with units of V/A